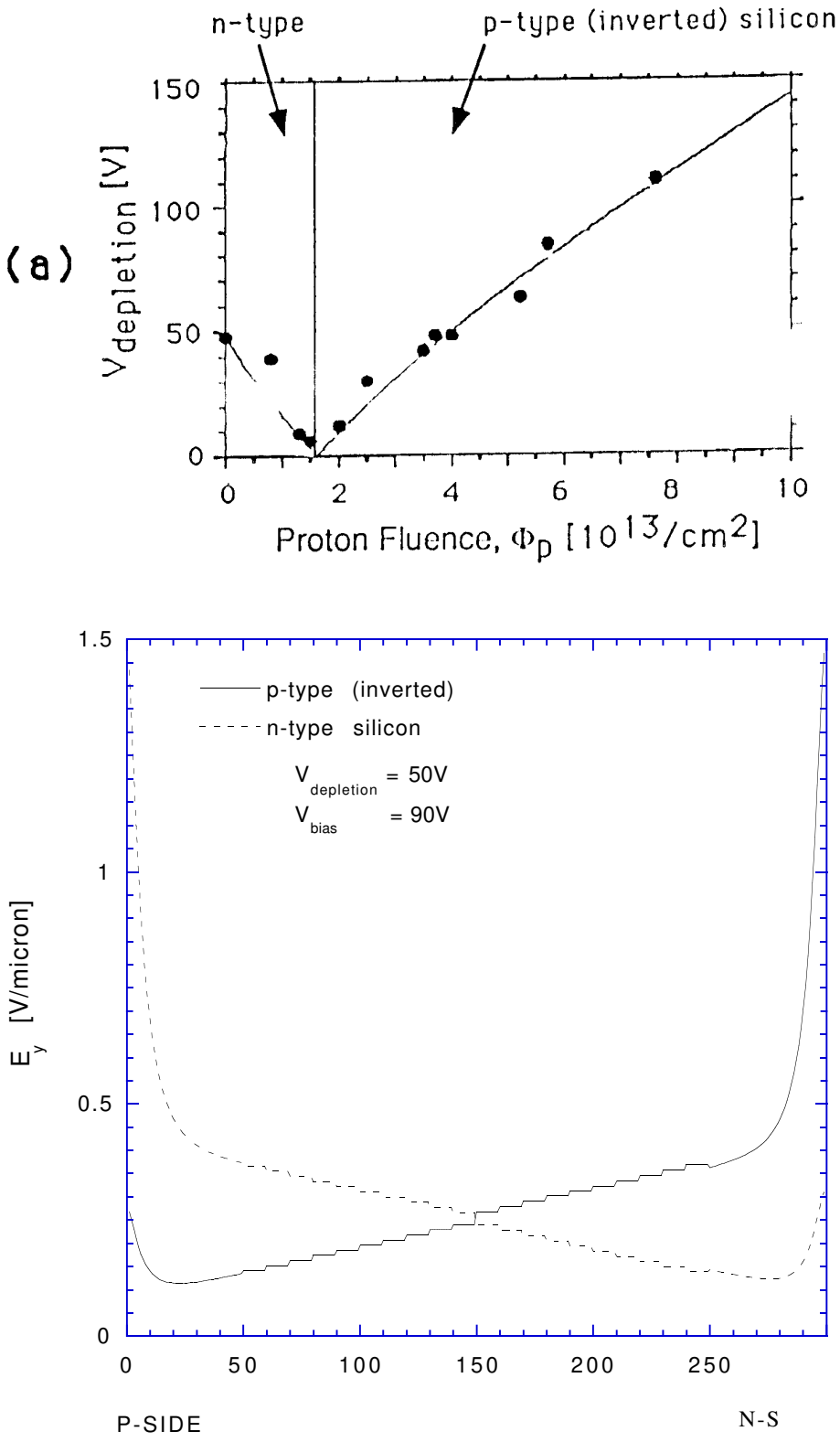

Fig. 10. (a) $V_{depletion}$ vs. proton fluence; (b) electric field in detector for n-type and p-type silicon